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Long duration storage of electronic components – Specification for implementation

Stockage longue durée des composants électroniques – Guide de mise en oeuvre

Langzeitlagerung von elektronischen Bauelementen – Spezifikation für die Ausführung

This Technical Specification was approved by CENELEC on 2005-12-03.

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CENELEC

European Committee for Electrotechnical Standardization Comité Européen de Normalisation Electrotechnique Europäisches Komitee für Elektrotechnische Normung

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Foreword

This Technical Specification was prepared by the Technical Committee CENELEC TC 107X, Process management for avionics.

The text of the draft was submitted to the formal vote and was approved by CENELEC as CLC/TS 50466 on 2005-12-03.

The following date was fixed:

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This document, which is in line with IEC/PAS 62435 relating to the management of obsolescence of electronic components, is first of all a practical guide to methods of long duration storage (more than 5 years) which summarizes the existing practices in the industry.

The application of the approach proposed in this guide in no way guarantees that the stored components are in perfect operating condition at the end of this storage. It only comprises a means of minimizing potential and probable degradation factors.

Unless otherwise specified, the approach, as well as the methods presented apply to all families of electronic components:

- passive components, including quartz crystals, connectors and relays. However, components with "manufacturer's" specifications showing an expiry date, or specific storage conditions, are excluded from this guide (e.g. primary cells, storage cells, etc...),
- encapsulated or non-encapsulated active components of a silicon [Si] or gallium arsenide [GaAs] technology,
- micro-electronic assemblies.

Contents

1	Gene	ral		5
2	Norm	ative refe	erences	5
3	Storag	ge decisi	ion criteria	6
	3.1	Advanta	ages of storage	6
		3.1.1	Technical simplicity – Rapidity	6
		3.1.2	Solution durability	6
		3.1.3	Preventive storage	6
	3.2	Hazards	s – Drawbacks	6
		3.2.1	Generic aging hazard	
		3.2.2	Poor stock dimensioning	7
		3.2.3	Incorrect control of reliability during storage	
		3.2.4	Freezing equipment functionalities	
	3.3	Storage	e cost (Annex C)	
	3.4	•	n criteria	
4	Purch		ocurement	
•	4.1	• .	components	
	4.2		y of components to be stored	
		4.2.1	Production stock	
		4.2.2	Field service stock	
	4.3		s it worth keeping in stock?	
	4.4		ement recommendations	
5			lidation of the components	
Ü	5.1		9	
	5.2	•	nt field	
	5.3		lection criteria	
	5.4		ements and tests	
	J. 4	5.4.1	Sampling	
		5.4.2	Visual examination, sealing, solderability	
		5.4.3	Compliance with the electrical specifications	
		5.4.5		
		E 4 4		
		5.4.4	Assessment of the supplied batch reliability	
		5.4.5	Manufacturing control check (technological analysis)	
•	5.5		n	
6			and storage	
	6.1		environment	
	6.2		tary storage unit	
	6.3		nanagement	
	6.4		lancy	
	6.5		cation - Traceability	
	6.6		ackaging	
	6.7		bility	
	6.8		ation bake	
	6.9	_	e conditions	
		6.9.1	Storage area	16
		6.9.2	Temperature	
		6.9.3	Temperature variations	
		6.9.4	Relative humidity - Chemical attacks - Contamination	
		6.9.5	Pressure	17
		6.9.6	Electrostatic discharges	17

	6.9.7 Vibrations – Mechanical impacts	
	6.9.8 Electromagnetic field - Radiation	17
	6.9.9 Light	17
6.10	Maintaining storage conditions	
7 Perio	odic check of the components	
7.1	Objectives	
7.2	Periodicity	
7.3	Tests during periodic check	
	ocking	
8.1	Precautions	
0.1	8.1.1 Electrostatic discharges	
	8.1.2 Mechanical impacts	
8.2	Inspection	
	fback	
i eeu	IDACK	19
Ληρον Λ	Evennle related to compenents	20
	- Example related to components	
	Example of a component list	
	- Examples of periodic and/or destocking tests	
	- Parameters influencing the final price of the component storage	
	- Parameters influencing the quantity of the components to be stored	25
Annex ⊨ -	- Failure mechanisms - Hermetically encapsulated and non-encapsulated active components	26
Annoy E	- Failure mechanisms: GaAs components	
Dibliogran	hy	20
Dibilograp		30
Tabla E	I. Failure machanisma. Harmatically available	
i abie E.	 Failure mechanisms - Hermetically encapsulated and non-encapsulated active components 	
		26
Table E		
	– Failure modes compared with initial table on the silicon devices	28
		28
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	– Failure modes compared with initial table on the silicon devices	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29
	Failure modes compared with initial table on the silicon devices Failure modes specific to GaAs components	28 29

1 General

Although it has always existed to some extent, obsolescence of electronic components, and particularly integrated circuits, has become increasingly intense over the last few years.

Indeed, with the existing technological boom, the commercial life of a component has become very short compared with the life of industrial equipment such as those encountered in the aeronautical field, the railway industry or the energy sector.

The many solutions enabling obsolescence to be resolved are now identified. However, selecting one of these solutions must be preceded by a case by case technical and economic feasibility study, depending on whether storage is envisaged for field service or production.

Remedial storage as soon as components are no longer marketed.

Preventive storage anticipating declaration of obsolescence.

Taking into account the expected life of some installations, sometimes covering several decades, the qualification times, and the unavailability costs, which can also be very high, the solution to be adopted to resolve obsolescence must often be rapidly implemented. This is why the solution retained in most cases consists in systematically storing components which are in the process of becoming obsolescent.

The technical risks of this solution are, a priori, fairly low. However, it requires the perfect mastery of the implemented process, and especially of the storage environment, although this mastery becomes critical when it comes to long term storage.

All handling, protection, storage and test operations should be performed in accordance with the technology requirements of the component.

2 Normative references

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

EN 190000:1995, Generic specification: Integrated monolithic circuits

EN 60068-2-17:1994, Environmental testing - Part 2: Tests - Test Q: Sealing (IEC 60068-2-17:1994)

HD 323.2.20 S3:1988, Basic environmental testing procedures - Part 2: Tests - Test T: Soldering (IEC 60068-2-20:1979 + A2:1987)

IEC 60410:1973, Sampling plans and procedures for inspection by attributes